Ka Band, Low Noise Amplifier
27.0 - 31.5 GHz

MAAL-011238
Preliminary - Rev. V2P

Features
- Low Noise Figure: 1.5 dB
- Gain: 30 dB
- P1dB: +11 dBm
- Bias Voltage: V_{DD} = 2 V
- Bias Current: I_{DSQ} = 25 mA
- 50 Ω Matched Input and Output
- 2 mm DFN 8-Lead Package
- RoHS* Compliant

Applications
- Satellite Communications
- Low Earth Orbit Space Payloads
- GEO High Throughput Satellite
- Radar
- EW

Description
The MAAL-011238 is an easy to use low noise amplifier. It operates from 27 GHz to 31.5 GHz and provides 1.5 dB noise figure, 30 dB gain and a P1dB of 11 dBm. The input and output are fully matched to 50 Ω with typical return loss >10 dB.

This product is fabricated using a GaAs pHEMT process which features full passivation for enhanced reliability.

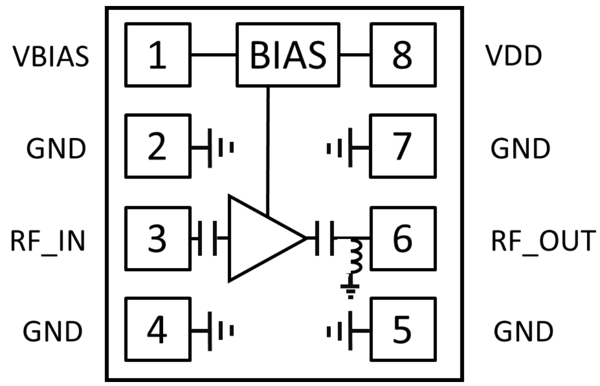
The MAAL-011238 can be used as a low noise amplifier stage or as a driver stage in higher power applications. This device is ideally suited for Ka-band satellite communication systems.

The MAAL-011238 is also available in die form under MAAL-011238-DIE part number.

Ordering Information

Part Number	Package
MAAL-011238	Pre-production

Functional Schematic



Pin Configuration[1]

Pin #	Function	Description
1	VBIAS	Bias Voltage
2, 4, 5, 7	GND	Ground
3	RF_{IN}	RF Input
6	RF_{OUT}	RF Output
8	VDD	Drain Supply
Paddle	GND[1]	Ground

1. The backside of the die must be connected to RF, DC and thermal ground.

Preliminary Information

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

Electrical Specifications: Freq. = 27.0 - 31.5 GHz, T_A = 25°C, V_D = 2 V, Z_0 = 50 Ω

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Small Signal Gain	P_{IN} = -20 dBm 27.0 GHz 31.5 GHz	dB	—	29 28	—
Small Signal Gain Variation over Temperature	—	dB/°C	—	0.02	—
Gain Flatness	—	dB	—	0.5	—
Noise Figure	—	dB	—	1.5	—
Input Return Loss	—	dB	—	10	—
Output Return Loss	—	dB	—	10	—
P1dB	27.0 GHz 31.5 GHz	dBm	—	10.5 11.0	—
Output 3rd Order Intercept	P_{IN} = -26 dBm/tone, 10 MHz spacing	dBm	—	20	—
Supply Current	—	mA	—	25	—

Absolute Maximum Ratings[2,3]

Parameter	Absolute Maximum
Input Power	18 dBm
Drain Voltage	4 V
Junction Temperature[4,5]	+160°C
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +125°C

2. Exceeding any one or combination of these limits may cause permanent damage to this device.
3. MACOM does not recommend sustained operation near these survivability limits.
4. Operating at nominal conditions with $T_J \leq +150°C$ will ensure MTTF > 1 x 10^6 hours.
5. Junction Temperature (T_J) = T_C + Θjc * (V * I)
   Typical thermal resistance (Θjc) = 93 °C/W.
   a) For T_C = +25°C,
      T_J = 31 °C @ 2 V, 32 mA
   b) For T_C = +85°C,
      T_J = 91 °C @ 2 V, 32 mA

Maximum Operating Conditions

Parameter	Maximum
TX Input Power	-14 dBm
V_{DD}	3.5 V
Junction Temperature[4,5]	+150°C
Operating Temperature	-40°C to +85°C

Handling Procedures

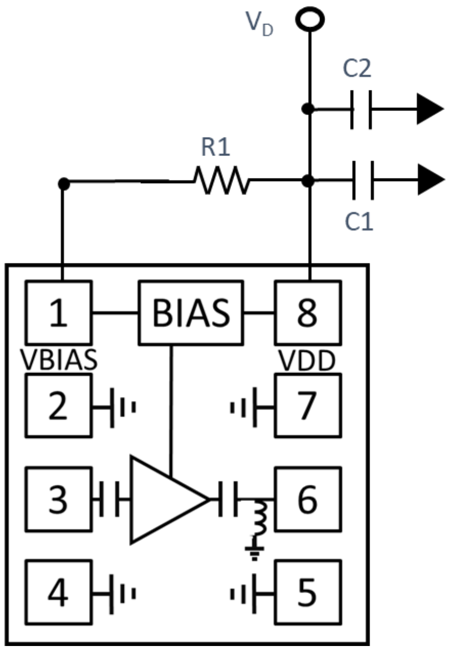
Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1A (250 V) devices.

Preliminary Information

Application Schematic



Parts List

Part	Value	Case Style
C1	100 pF	0402
C2	0.1 µF	0402
R1	500 Ω	0402

Application Circuit and Operation

The basic application circuit is shown below. Place C1 capacitor as close to the package as physically possible. The position of the C2 capacitor is not as critical but should also be placed as closely as practically possible.

Operating the MAAL-011238

Turn-on

1. Apply V_D (+2 V)
2. Set I_{DQ} (25 mA) by adjusting R1
3. Apply RF_{IN} signal

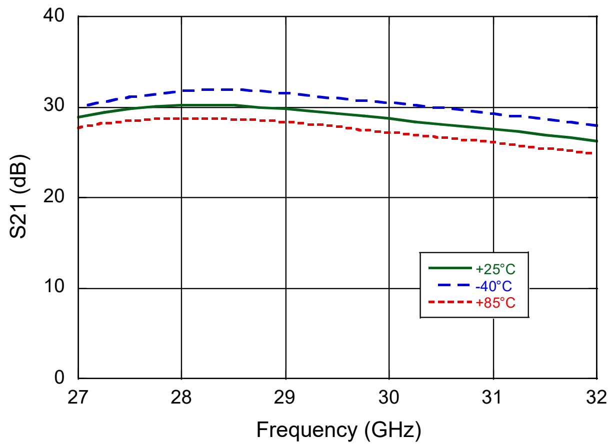
Turn-off

1. Remove RF_{IN} signal.
2. Decrease V_D to 0 V

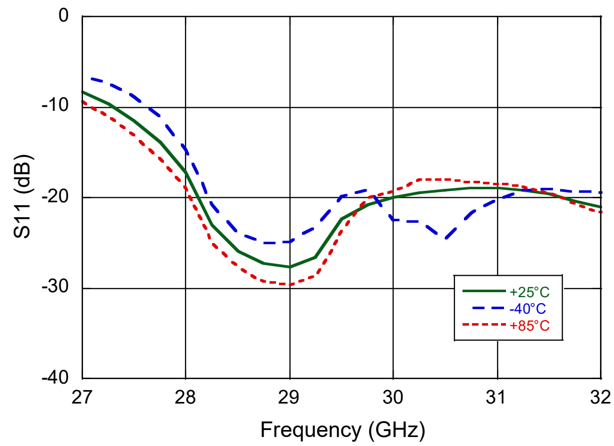
Preliminary Information

Typical Performance Curves @ V_D = 2 V, I_D = 25 mA, Z_0 = 50 Ω

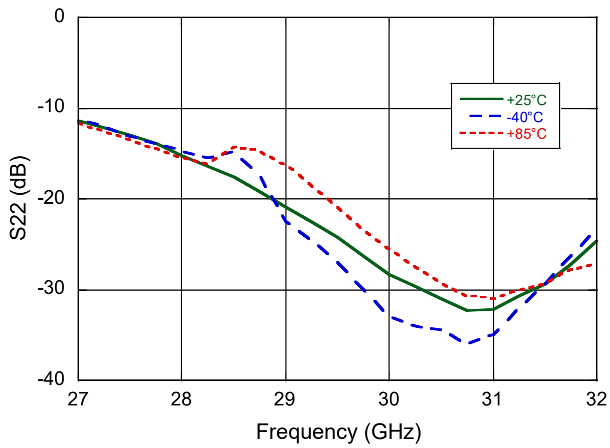
Gain



Input Return Loss



Output Return Loss



Preliminary Information

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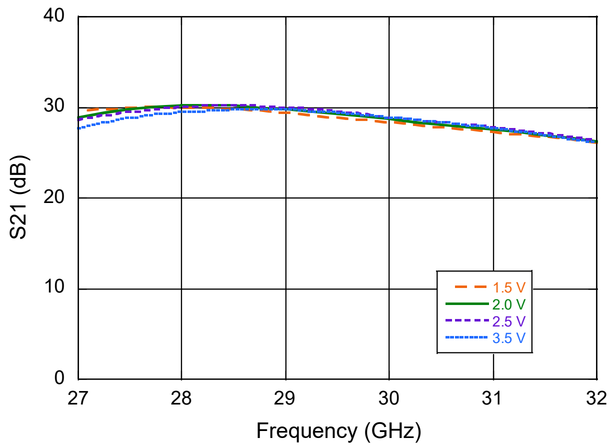
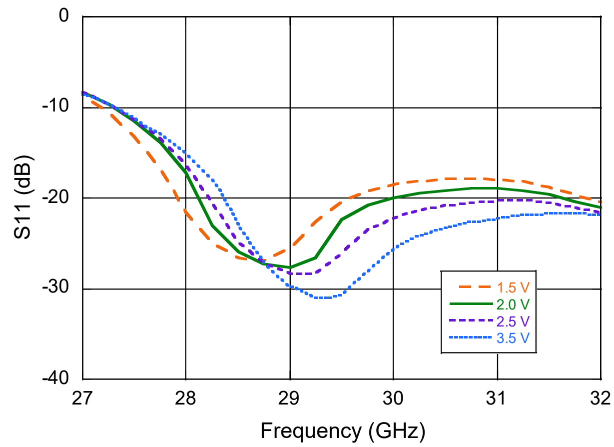
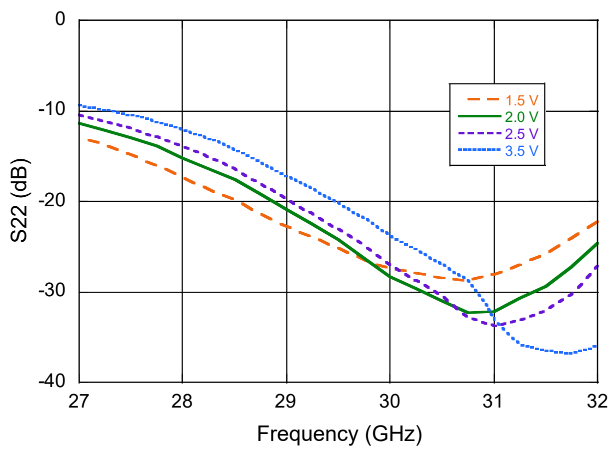
Gain



Input Return Loss



Output Return Loss



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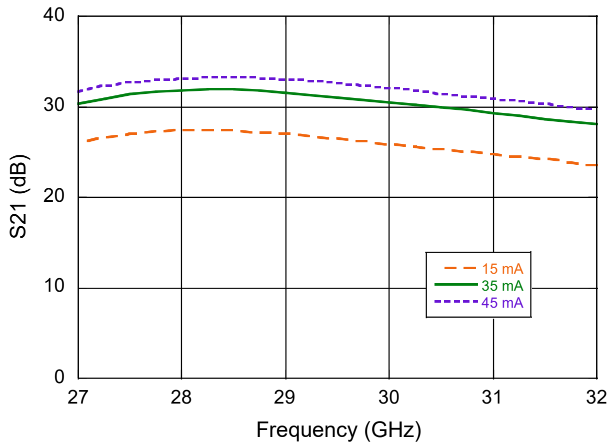
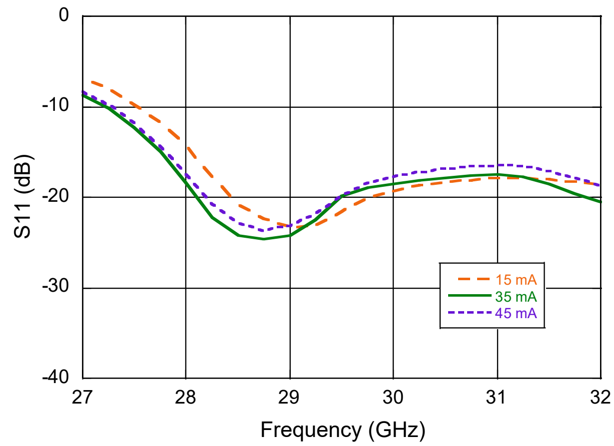
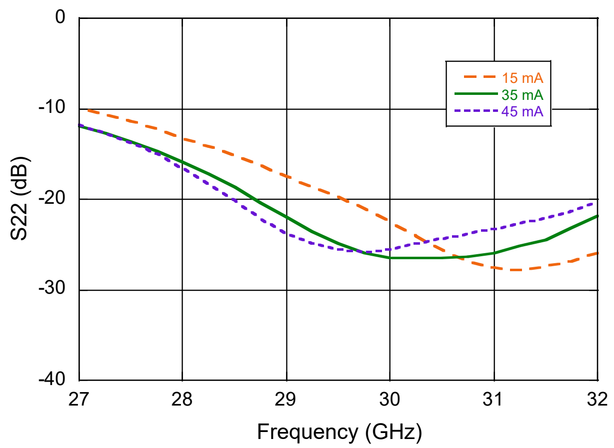
Gain



Input Return Loss

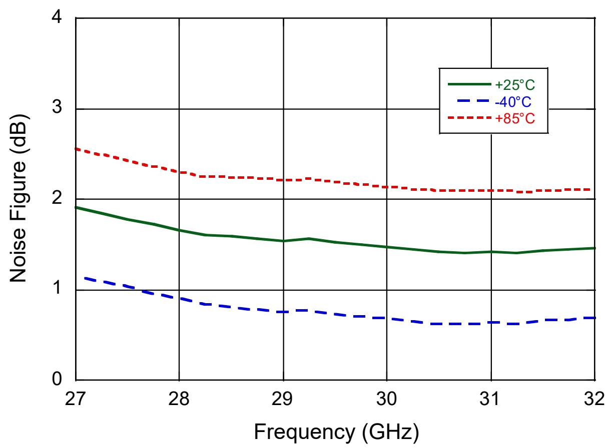


Output Return Loss

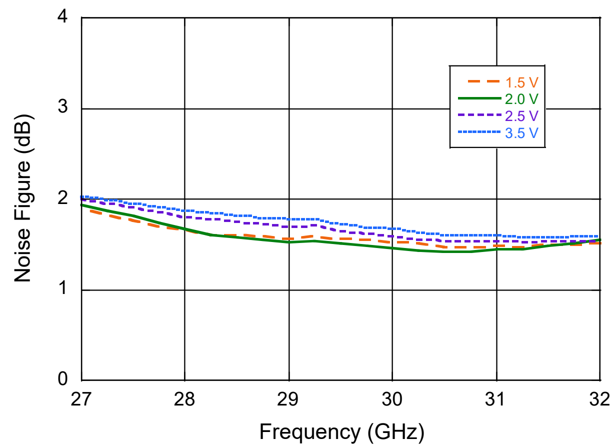


Typical Performance Curves @ V_D = 2 V, I_D = 25 mA, 25°C, Z_0 = 50 Ω

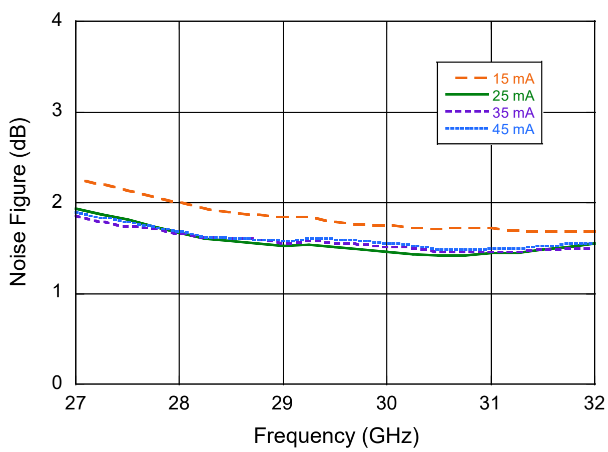
Noise Figure over Temperature



Noise Figure over Voltage



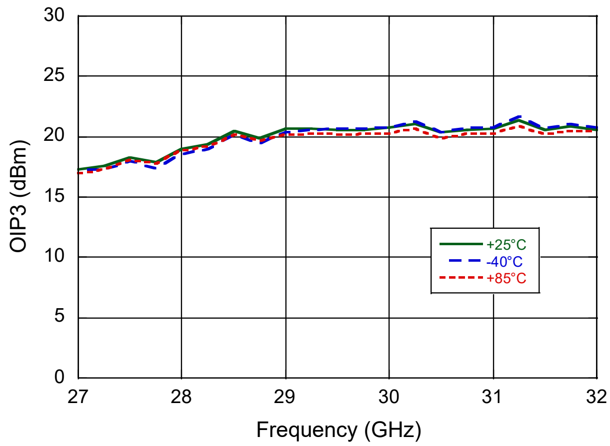
Noise Figure over Current



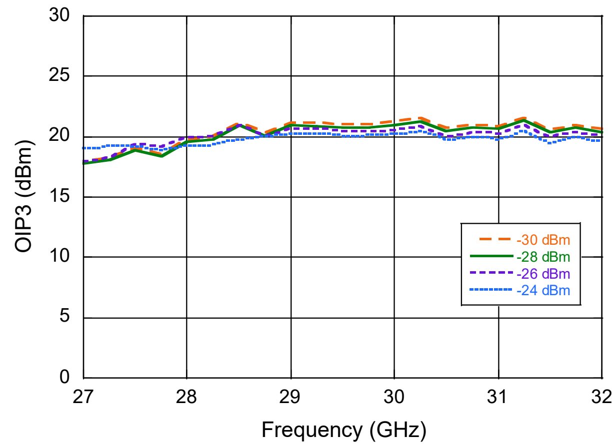
Preliminary Information

Typical Performance Curves @ V_D = 2 V, I_D = 25 mA, P_{IN} = -30 dBm, 25°C, Z_0 = 50 Ω

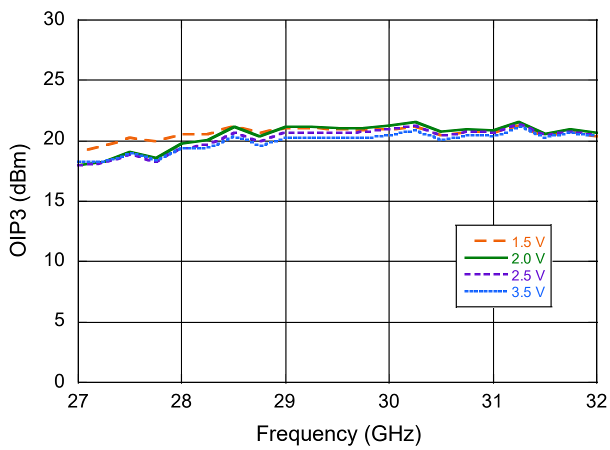
OIP3 over Temperature



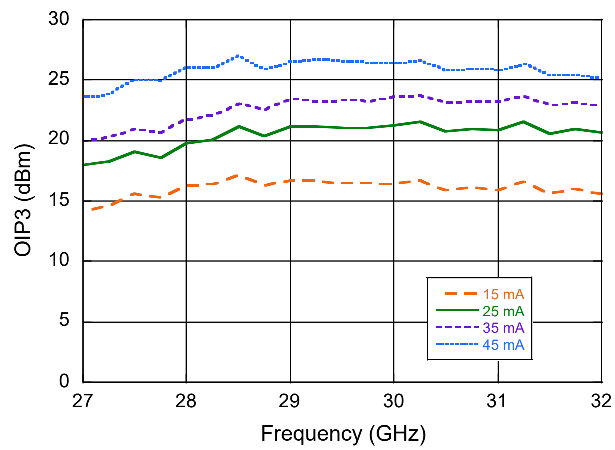
OIP3 over Input Power



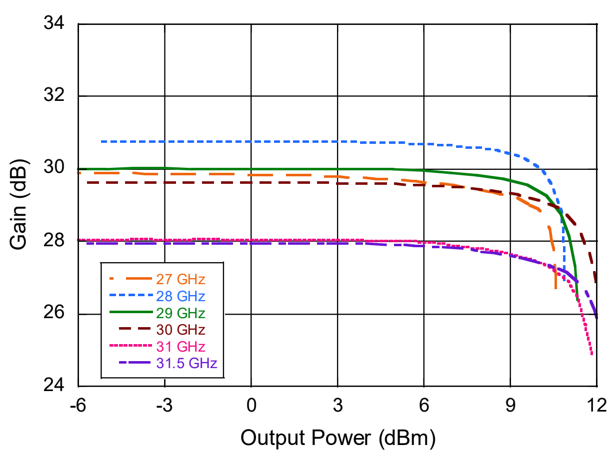
OIP3 over Bias Voltage



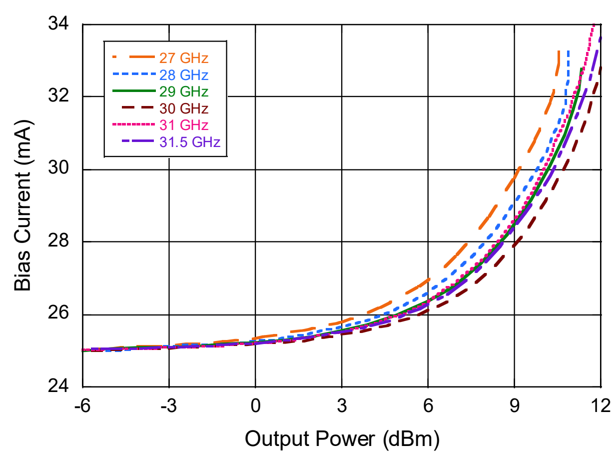
OIP3 over Bias Current



Gain vs Output Power over Frequency



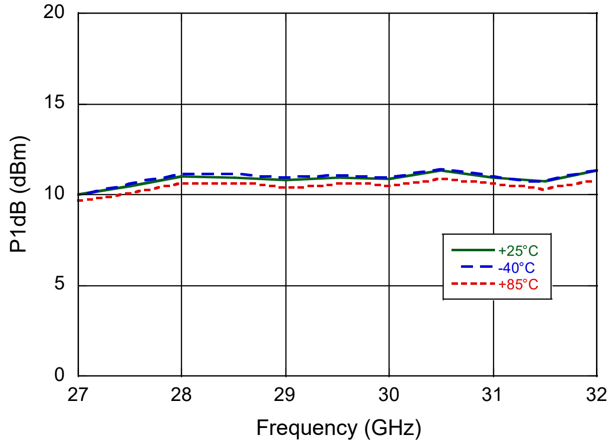
Bias Current vs Output Power over Frequency



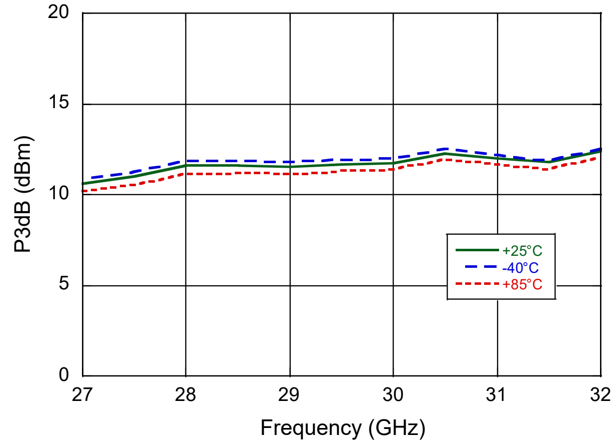
Preliminary Information

Typical Performance Curves @ V_D = 2 V, I_D = 25 mA, 25°C, Z_0 = 50 Ω

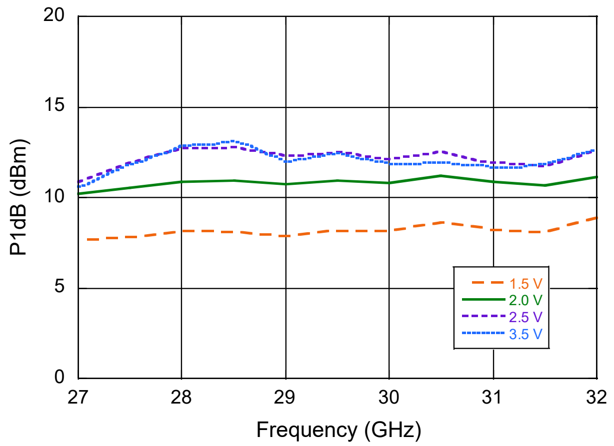
P1dB over Temperature



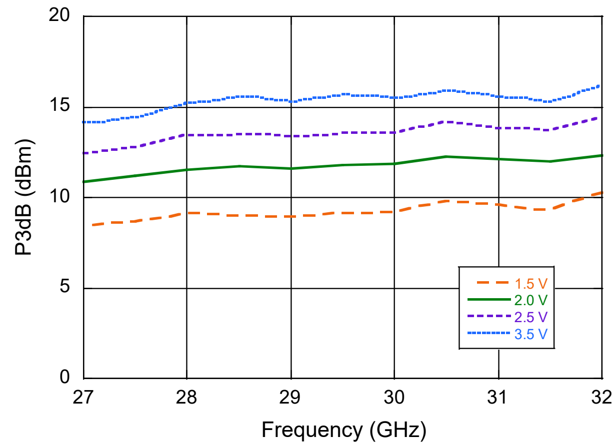
P3dB over Temperature



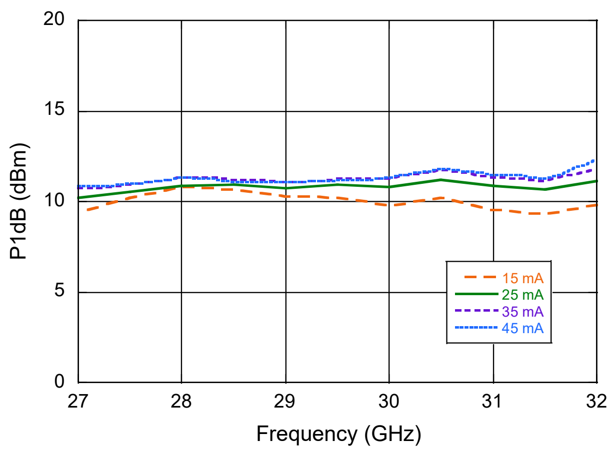
P1dB over Bias Voltage



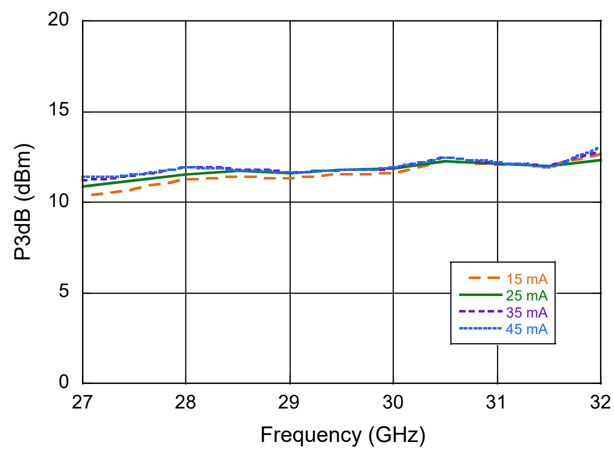
P3dB over Bias Voltage



P1dB over Bias Current

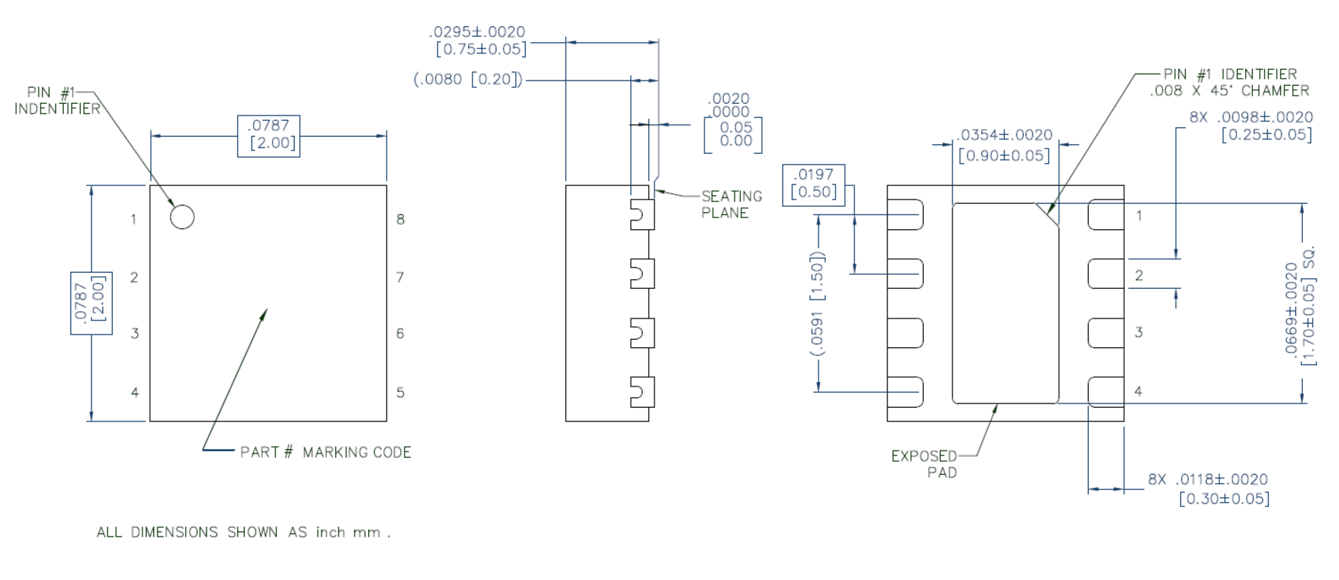


P3dB over Bias Current



Preliminary Information

Lead-Free 2 mm DFN 8-Lead SMT[9,10,11,12]



9. All units in in (mm), unless otherwise noted, with a tolerance of .xxxx = ±.0005 in and .xxx = ±.005 in.
10. Lead finish: NiPdAu plating
11. Reference Application Note S2083 for lead-free solder reflow recommendations.
12. Meets JEDEC moisture sensitivity level 1 requirements.

Preliminary Information